"Characterization of nanoporous materials by positron annihilation spectroscopy"

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Characterization of nanoporous materials by positron annihilation spectroscopy

- Positron annihilation lifetime spectroscopy (PALS)
- Application in crystalline materials
- Positronium as bound state of Positron and Electron
- Characterization of nanopores by Positronium lifetime spectroscopy

Basics of Lifetime Spectroscopy







Lifetime Measurement



Positron lifetime: time between 1,27 MeV and 0,511 MeV quanta

Lifetime Spectrum



- lifetime spectra consist of exponential decay components
- positron trapping in open-volume defects leads to long-lived lifetime components
- spectra analysis is performed by non-linear fitting routines after source and background subtraction
- experimental result: lifetimes τ_{i} and intensities \mathbf{I}_{i}

$$N(t) = \sum_{i=1}^{k+1} \frac{I_i}{\tau_i} \exp\left(-\frac{t}{\tau_i}\right)$$

Defects in electron irradiated Ge



- electron irradiation (2 MeV) at 4K generates Frenkel pairs
- vacancy annealing and defect reactions may be studied

(Polity et al., 1997)

Typical lifetimes



Thermalization



- broad positron emission spectrum
- deep implantation into solids
- not useful for thin layers
- moderation necessary

Mean implantation depth of unmoderated positrons (1/e) in Si: 50μ m

Slow positron beam at Halle



- spot diameter: 5 mm
- time per single spectrum: 20 min
- time per defect-depth scan: 12 hours



Pick-off Annihilation of o-Ps



pick-off annihilation

- o-Ps is converted to p-Ps by capturing an electron with anti-parallel spin
- happens during collisions at walls of pore
- lifetime decreases rapidly
- lifetime is function of pore size 1 ns ... 142 ns



• Pore size < 1 nm -> $\lambda_{3\gamma}$ neglected, only pick off annihilation

$$\lambda_{TE}(R) = \lambda_A \left[1 - \frac{R}{R + \Delta R} + \frac{1}{2\pi} \sin\left(\frac{2\pi R}{R + \Delta R}\right) \right]$$

- $\Delta R = 0.166$ nm determined by Eldrup
- Pore size > 1 nm -> $\lambda_{3\gamma}$ can not be neglected, temperature dependence of o-Ps lifetime (excited states)

The 2 models for R > 1 nm - Tokyo

• Tokyo model:
$$\lambda_{Tokyo}(R) = \begin{cases} \lambda_{TE} + \lambda_{3\gamma} & (R < R_a) \\ \lambda_{TE}(R_a) \left[1 - \left(\frac{R - R_a}{R + \Delta R}\right)^b \right] + \lambda_{3\gamma} & (R \ge R_a) \end{cases}$$

<u>Problems</u>: - no explicit temperature dependence

- two free parameters to be determined



K. Ito, H. Nakanishi, Y. Ujihira, J. Phys Chem. B 1999, 103, 4555.

The 2 models for R > 1 nm - RTE

RTE model (for 3D cubic pores):





- Boltzmann statistics ascribes explicit temperature dependence to the lifetime
- Rectangular geometry -> prevention of complicated Bessel functions
- δ = 0.18 nm analogous to TE model

D. W. Gidley, T. L. Dull, W. E. Frieze, J. N. Sun, A. F. Yee, J. Phys. Chem. B 2001, 105, 4657.



The experiments at T = 300 K



- we measured porous glass in a broad pore size range
- pore size obtained by N₂adsorption method
- for T=300 K general agreement to the RTE model
- calibration curve for the correlation of o-Ps lifetime and pore size

Temperature Dependence

- although we found good agreement for T = 300 K
- temperature behavior cannot be explained very well at low temperatures
- model too simple



Observation of cryo-condensation in nano-pores



- S-parameter behaves similar like intensity of o-Ps lifetime component
- cryo-condensation can be observed as filling of pores
- phase transition can be studied in a nano-volume as function of size, gas, T and p

Summary

- Time spectroscopy of o-Ps is a very sensitive tool for characterization of nano-pores
- most sensitive in range 0.5 ... 30 nm
- closed and open pores
- positron beam can be used: fully non-destructive (no contact to sample)